

L Number	Hits	Search Text	DB	Time stamp
1	6	(("5627403") or ("6051497") or ("5788767")).PN.	USPAT; US-PGPUB; EPÖ; JPO; DERWENT; IBM_TDB	2004/05/07 13:34
2	28	(oxide same HDPCVD) and EEPROM	USPAT; US-PGPUB; EPÖ; JPO; DERWENT; IBM_TDB	2004/05/07 13:12
3	3584	((438/216) or (438/257) or (438/261) or (438/287) or (438/591) or (438/769) or (438/954) or (438/981)).CCLS.	USPAT; US-PGPUB; EPÖ; JPO; DERWENT; IBM_TDB	2004/05/07 13:22
4	3	((438/216) or (438/257) or (438/261) or (438/287) or (438/591) or (438/769) or (438/954) or (438/981)).CCLS.) and ("silicon-oxy-nitride" or (silicon near oxide near nitride)) with (passivat\$4 near layer)	USPAT; US-PGPUB; EPÖ; JPO; DERWENT; IBM_TDB	2004/05/07 13:25
5	610	silicon near oxy-nitride	USPAT; US-PGPUB; EPÖ; JPO; DERWENT; IBM_TDB	2004/05/07 13:25
6	60	(silicon near oxy-nitride) and ((Mask near ROM) or (flash near memory))	USPAT; US-PGPUB; EPÖ; JPO; DERWENT; IBM_TDB	2004/05/07 14:29
7	379	((Mask near ROM) with (flash near memory))	USPAT; US-PGPUB; EPÖ; JPO; DERWENT; IBM_TDB	2004/05/07 14:30
8	673	((Mask near ROM) with (EPROM))	USPAT; US-PGPUB; EPÖ; JPO; DERWENT; IBM_TDB	2004/05/07 14:30